## Principles of Electronics Design 521431A

Exam 12/18/2007

- 1. Following questions are related to Fig. 1 and you can assume that  $U_{BE} = 0.6 \text{ V}$ .
  - (a) Find the gain of the operational amplifier configuration  $u_{opa}/u_{in}$  and the input impedance.
  - (b) Find the gain of the emitter follower  $u_{out}/u_{opa}$  and the output impedance.
  - (c) What is the total gain of the configuration  $u_{out}/u_{in}$ ?
  - (d) The input signal  $u_{in}$  is a sine-wave with amplitude of 10 mV, draw signals  $u_{opa}$  and  $u_{out}$  in the same figure.
  - (e) How many decibels the output signal attenuates if  $8 \Omega$  load is connected to the output?

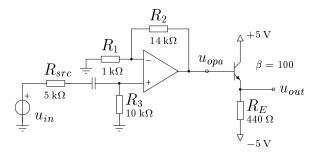


Figure 1: Figure for question 1.

2. Select component values for common source amplifier of Fig. 2 to meet the following specifications:  $R_{out} = 1 \,\mathrm{k}\Omega$ ,  $R_{in} > 100 \,\mathrm{k}\Omega$ ,  $U_D = 4 \,\mathrm{V}$ ,  $u_{out}/u_{in} > 10$ . Transistor parameters:  $K_n = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} = 2 \,\mathrm{mA/V^2}$  and  $U_t = 1 \,\mathrm{V}$ . Capacitors  $C_1$ ,  $C_2$  and  $C_3$  are large coupling capacitors. (6p)

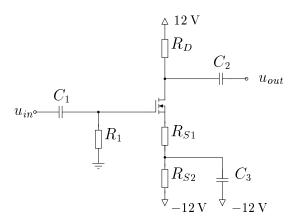


Figure 2: Figure for question 2.

$$i_D = \frac{1}{2}\mu_n C_{ox} \frac{W}{L} (u_{GS} - U_t)^2$$

$$g_m = \frac{\partial i_D}{\partial u_{GS}}|_{u_{GS} = U_{GS}} = \mu_n C_{ox} \frac{W}{L} (U_{GS} - U_t)$$

- 3. (a) Define the operation of a diode, biased both in forward- and reverse directions (voltage/current, temperature effect) either drawing the curve or using a formula and also using words. (2p)
  - (b) Present the ideal model of a diode and define, what means and how you would calculate the value of the dynamic resistance of a diode. (2p)
  - (c) How would you make a half-bridge rectifier using a diode? Draw the schematic diagram and explain its operation. (2p)
- 4. (a) Draw the schematic diagram and the transfer function of a CMOS inverter (using a curve  $V_{IN}$ - $V_{OUT}$ ) and explain the operation state of the transistors in the different parts of the curve. (2p)
  - (b) On which basis and how would you calculate the sizes of the transistors of the CMOS inverter? (2p)
  - (c) The schematic diagram of a double integral A/D-converter is presented in Figure 3. Define using words, how it works and draw the voltages in points  $-V_S$ ,  $V_{ref}$  and  $V_x$  as a function of time. (2p)

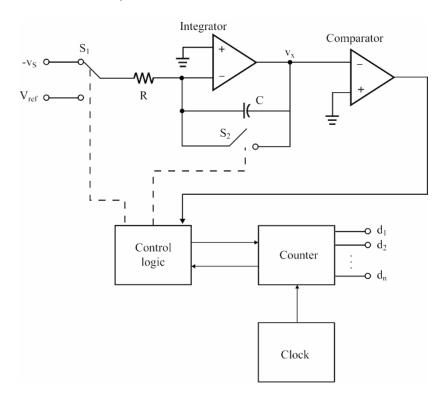


Figure 3: Figure for question 4.